



## **Dual N-Channel 20-V (D-S) MOSFET**

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$ $I_{D}\left(A\right)$			
20	0.030 at V <sub>GS</sub> = 4.5 V	7.7		
	0.036 at V <sub>GS</sub> = 2.5 V	7.0		
	0.045 at V <sub>GS</sub> = 1.8 V	6.3		

#### **FEATURES**

- Halogen-free Option Available
- TrenchFET<sup>®</sup> Power MOSFETS: 1.8 V Rated
- New Low Thermal Resistance PowerPAK<sup>®</sup> Package with Low 1.07 mm Profile

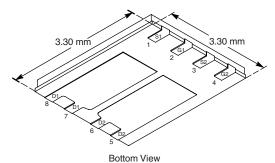


RoHS

#### **APPLICATIONS**

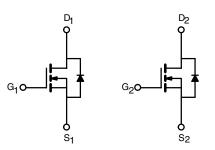
· HDD Spindle Drive

#### PowerPAK 1212-8



Ordering Information: Si7904DN-T1-E3 (Lead (Pb)-free)

Si7904DN-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATING</b>	<b>S</b> T <sub>A</sub> = 25 °C, ur	nless otherwise	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	20		V
Gate-Source Voltage		V <sub>GS</sub>	± 8		
Continuous Dunin Comment /T 150 %C\d	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	7.7	5.3	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 85 °C		5.5	3.8	
Pulsed Drain Current		I <sub>DM</sub>	20		Α
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.3	1.1	
Single Pulse Avalanche Current		I <sub>AS</sub>	15		
Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	11		mJ
Mariana Danie Diada diada	T <sub>A</sub> = 25 °C		2.8	1.3	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 85 °C		1.5	0.85	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations <sup>b,c</sup>		<u> </u>	260		

THERMAL RESISTANCE RA	ATINGS				
Parameter		Symbol	Typical	Maximum	Unit
Manipulation to Applicate	t ≤ 10 s	R <sub>thJA</sub>	35	44	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		75	94	
Maximum Junction-to-Case	Steady State	R <sub>th,IC</sub>	4	5	]

#### Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile (<a href="http://www.vishay.com/ppg?73257">http://www.vishay.com/ppg?73257</a>). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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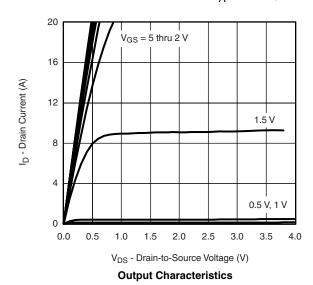
SPECIFICATIONS T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 935 \mu A$	0.45		1.0	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 20 V, V <sub>GS</sub> = 0 V			1		
		$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	20			Α	
		$V_{GS} = 4.5 \text{ V}, I_D = 7.7 \text{ A}$		0.025	0.030	Ω	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 7.0 \text{ A}$		0.030	0.036		
		$V_{GS} = 1.8 \text{ V}, I_D = 1 \text{ A}$		0.037	0.045		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.7 A		23		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 2.3 A, V <sub>GS</sub> = 0 V		0.70	1.2	V	
Dynamic <sup>b</sup>					•		
Total Gate Charge	$Q_g$			10.2	15		
Gate-Source Charge	$Q_{gs}$ $V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 7.7 \text{ A}$		1.3		nC		
Gate-Drain Charge	$Q_{gd}$			2.4			
Turn-On Delay Time	t <sub>d(on)</sub>			15	23		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 10 V, $R_L$ = 10 $\Omega$		50	75	1	
Turn-Off DelayTime	t <sub>d(off)</sub>	$I_D\cong$ 1 A, $V_{GEN}$ = 4.5 V, $R_G$ = 6 $\Omega$		60	90	ns	
Fall Time	t <sub>f</sub>			45	68		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 2.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		40	80		

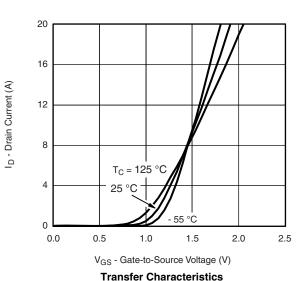
#### Notes:

- a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}\text{C}$ , unless otherwise noted



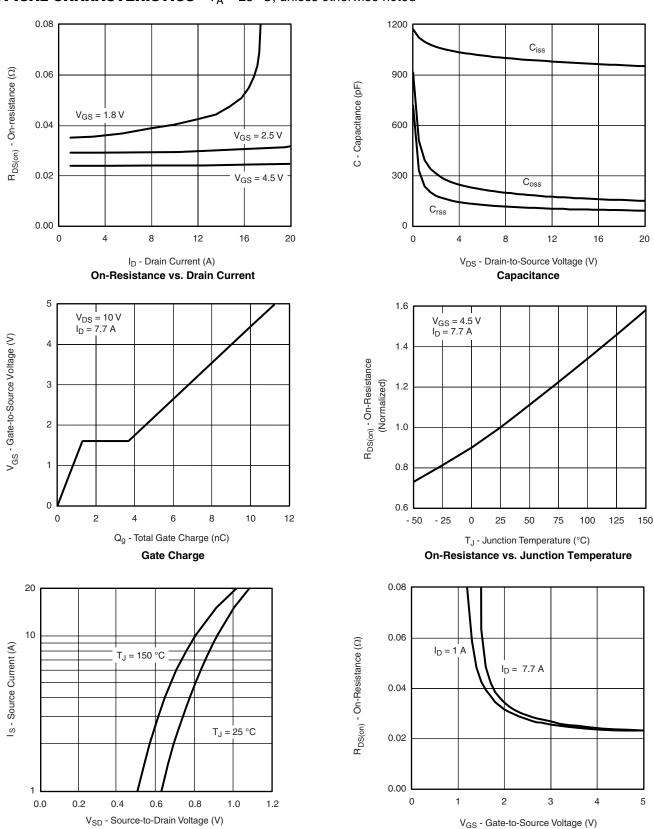








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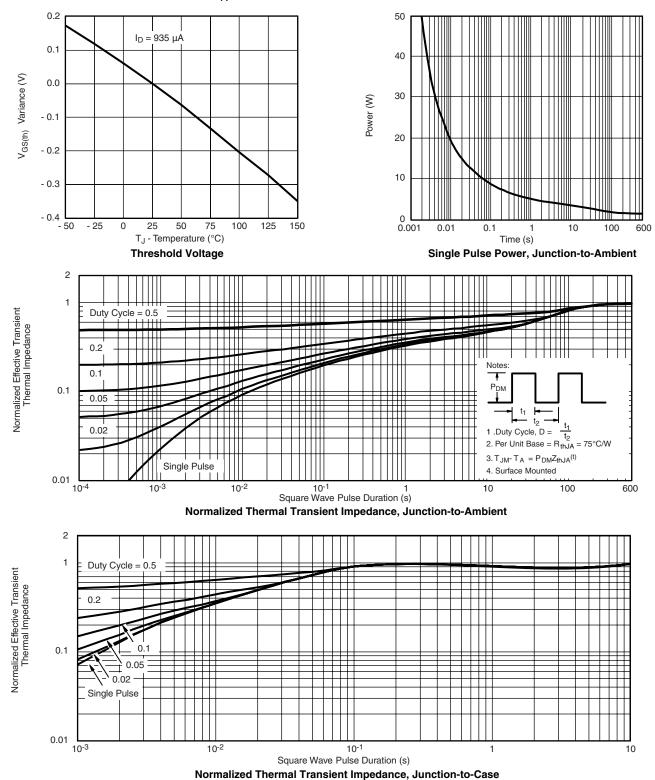
Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

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